

Low Energy Particle Detector: Laser Induced **DORELAS**

- **Fisica vs Rivelatori a Bassa Soglia di Energia**
- **Da KeV a eV Breve sguardo d'insieme e prospettive**
- **Pompaggio Laser su “ Mezzo Attivo “ : RIVELATORE**

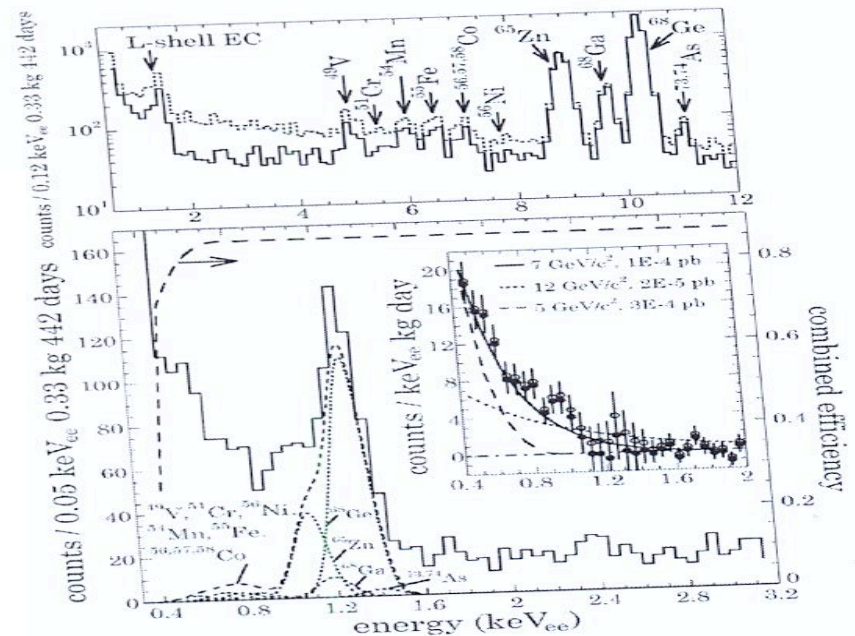
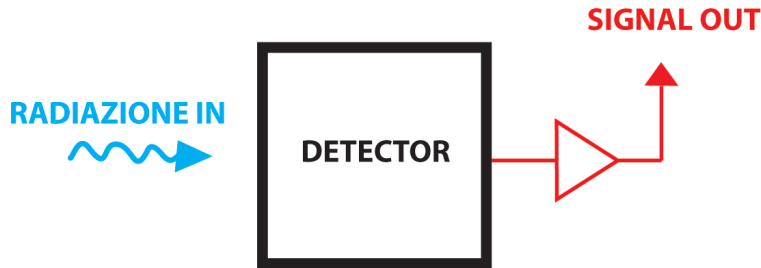
IL Fatto e il da Farsi

- **Richieste : Finanziarie ,Servizi ,**

Stato Attuale Rivelatori Basse Soglie

$$\text{Segnale} \propto E_{\text{rilasciata}} / w_{\text{detector}} \quad (\text{Fano Factor, Quenching Factor, ...})$$

$$W \approx 2,5 E_{\text{gap}} \quad \text{Shockley}$$



Scintillatori : Kev (40 ph/KeV) Q.F. elevato alle basse energie , F.F. alto

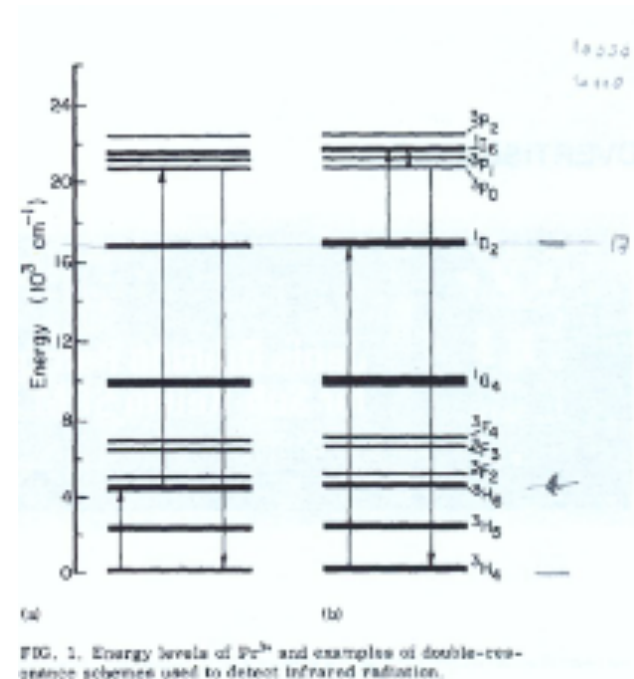
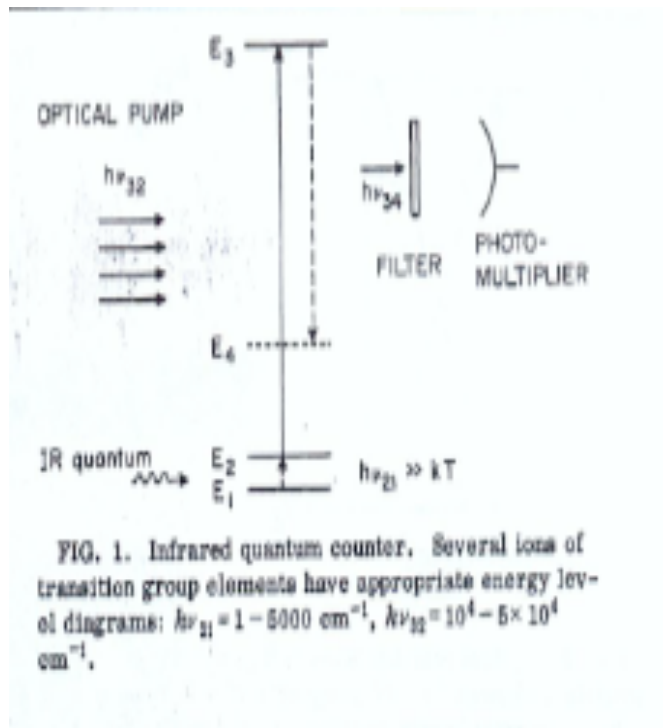
Semiconduttori : 400 eV (1 e/h /3,6 eV Si , 100 elettroni rumore a bassa Capacita')

Bolometri : 100 eV (Capacita termica totale, basse soglie piccole masse e milliKelvin)

Infrared Quantum Counter Idea

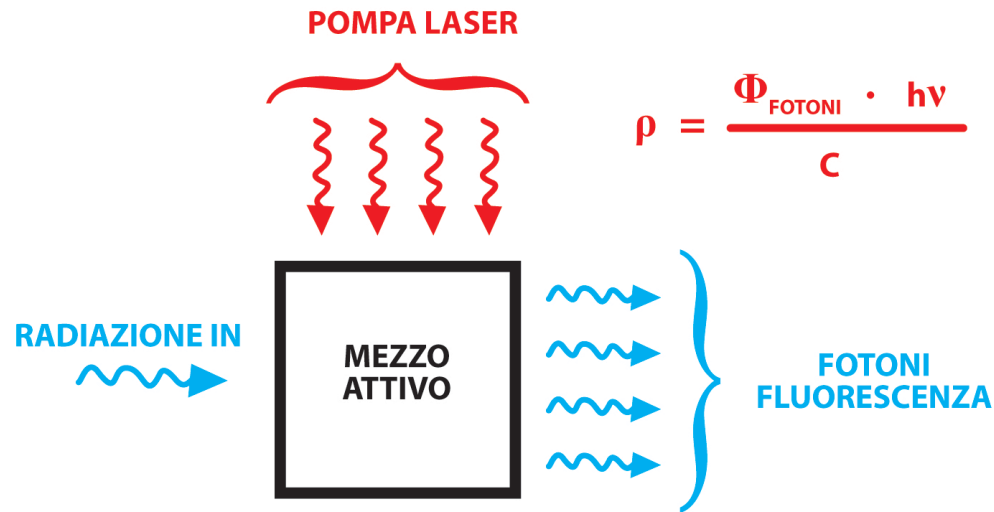
Bloembergen (Nobel Prize) suggested to detect IR photons with large Q.E.

where No Phototube are available at IR wavelength (PRL '59)



Actual Quantum Efficiency for 10 micron IR photons almost at 100% level

A New Detector Approach for Low Energy Release

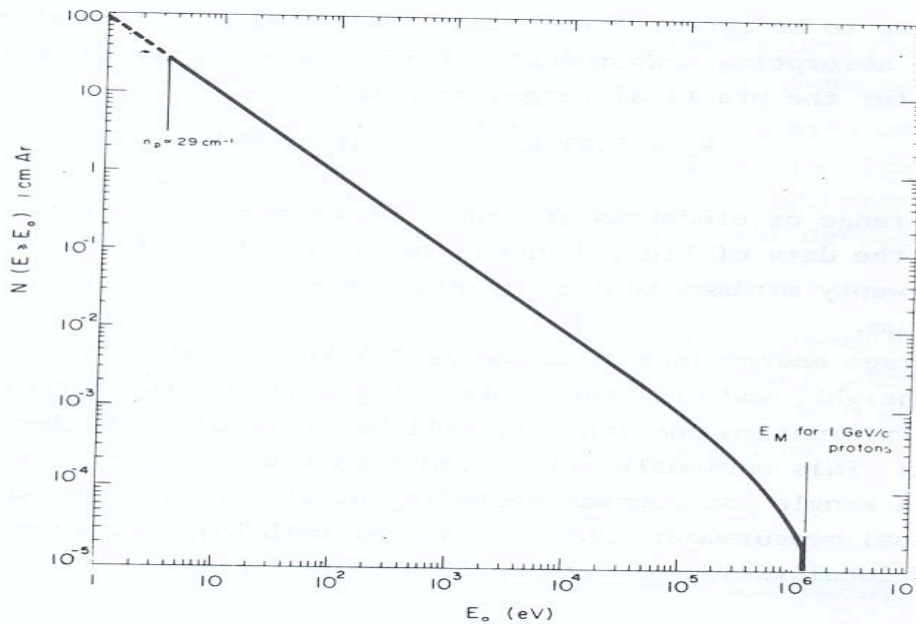


Radiazione in Attraverso dE/dx Promuove atomi su stati eccitati

Maggior probabilita' $P(e) = 1/E^2$ su stati di bassa energia

Campo Cristallino Mezzo Attivo rimuove la degenerazione sullo stato fondamentale

Generando primi stati eccitati a livelli di 10 meV



$$P(E)dE = \frac{K}{\beta^2} \frac{Z}{A} \frac{x}{E^2} dE = W \frac{dE}{E^2} \quad .$$

Scattering elettronici su Fononi Ottici

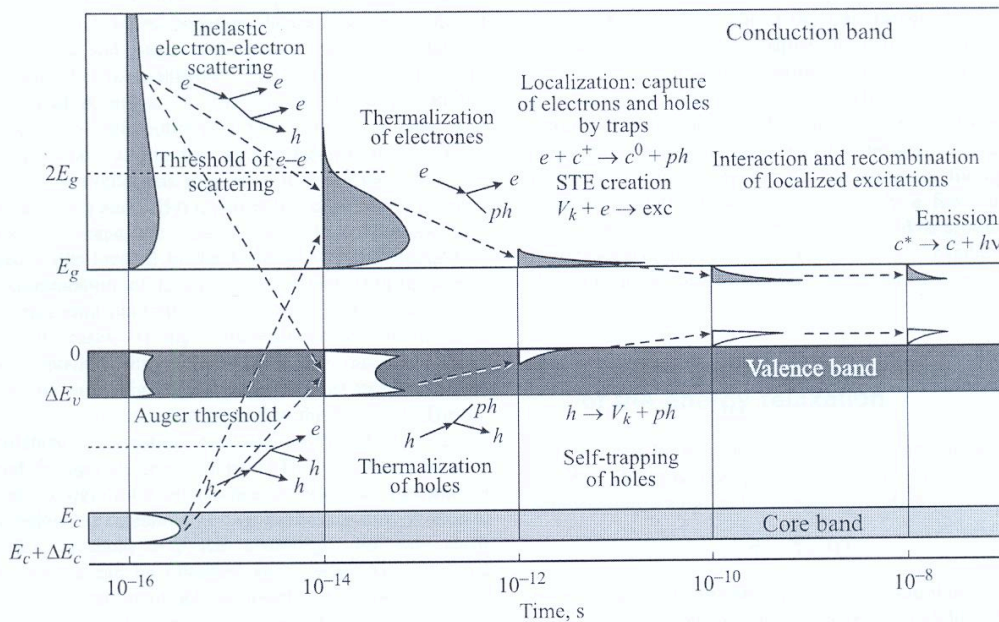
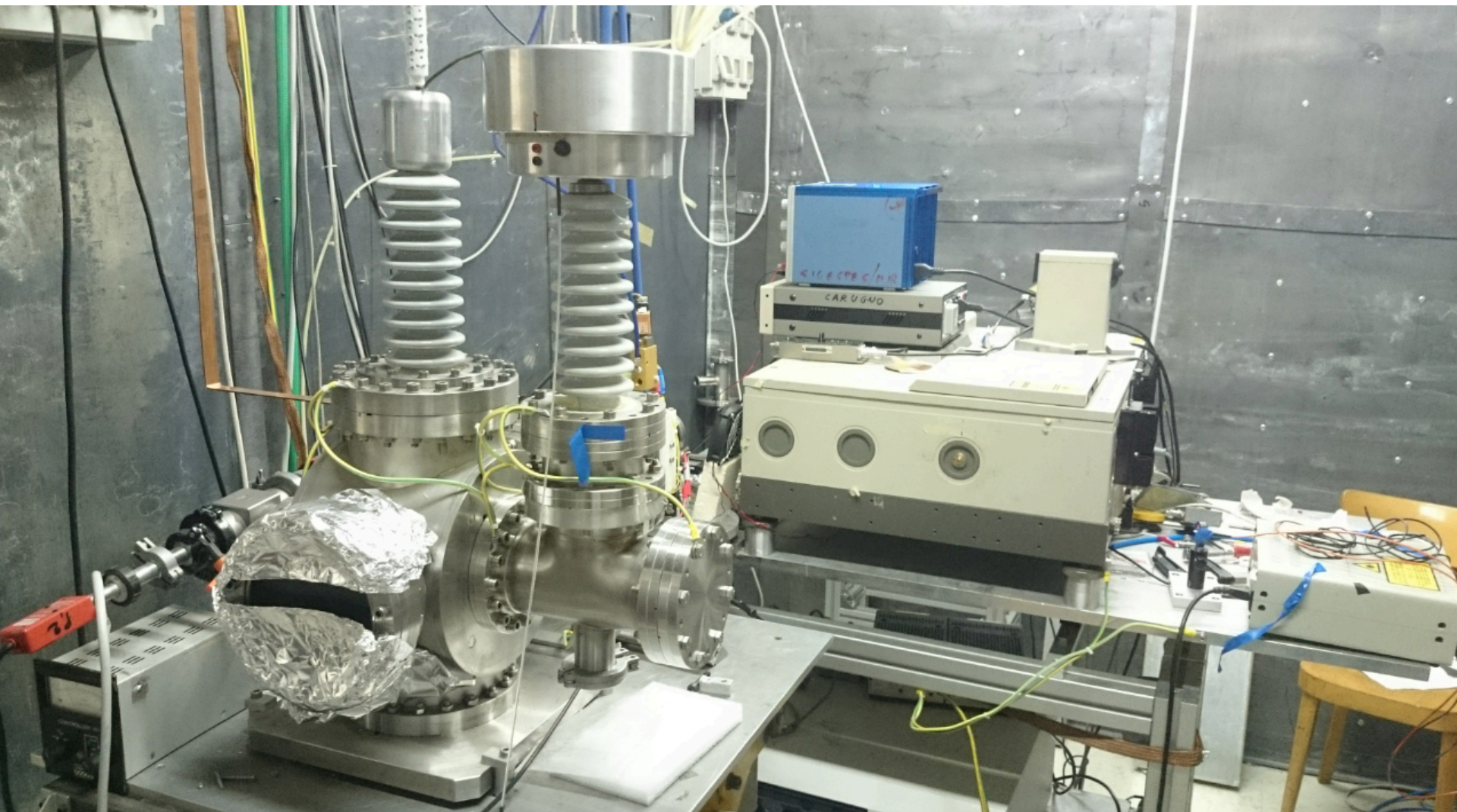


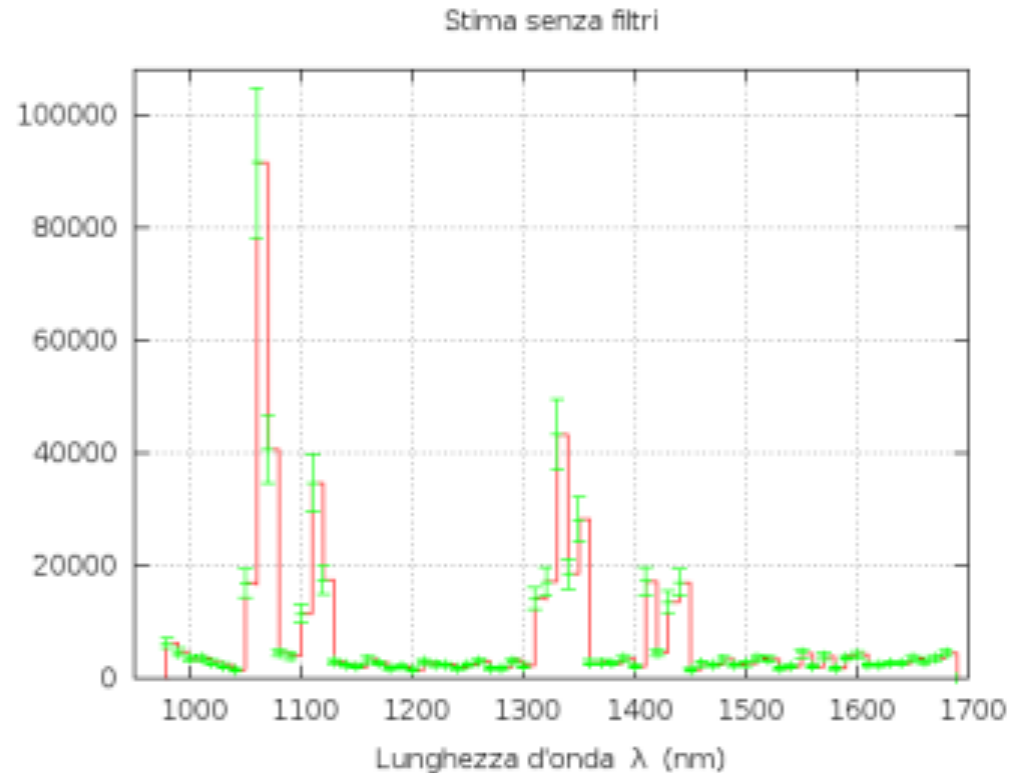
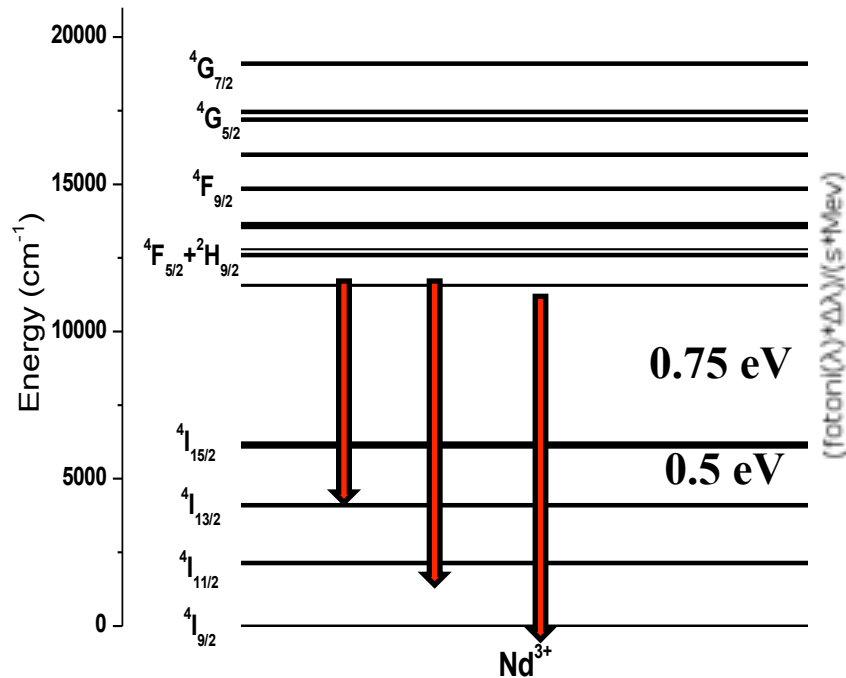
Figure 1. General scheme of relaxation of electronic excitations in an insulating material.

Electron Irradiation Facility @ Legnaro



Nd:YAG IR Transitions and Spectra

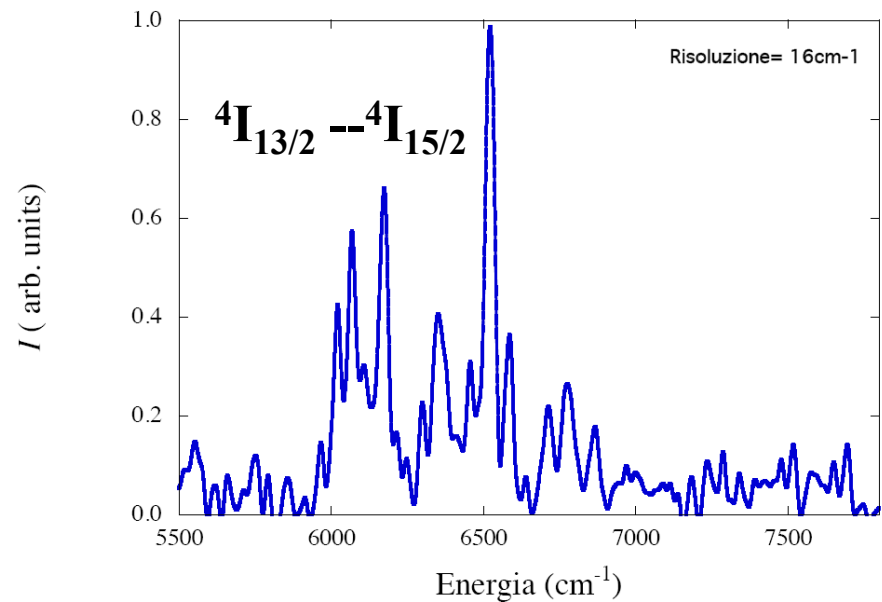
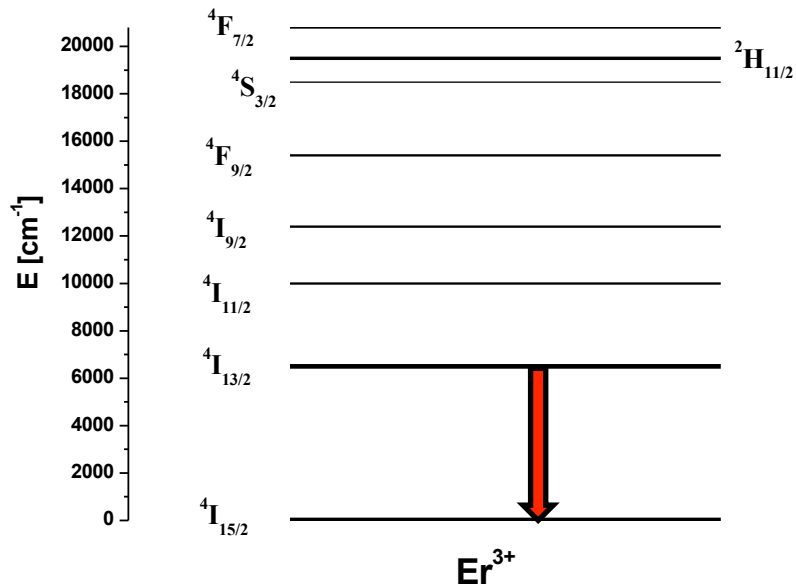
At Room Temperature



IR Emission Efficiency larger than 15%

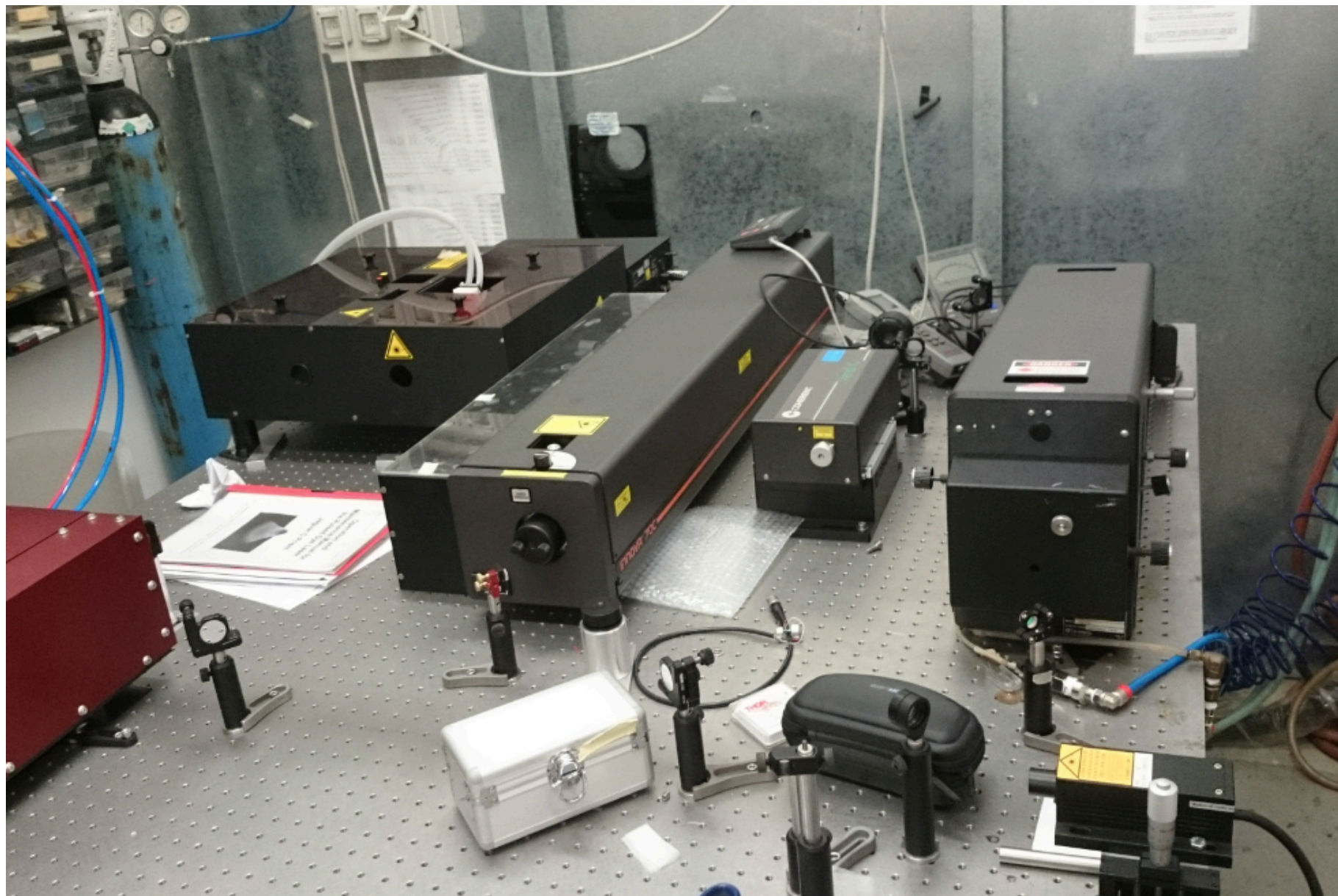
Erbium:Yag Emission Spectrum

0,4% Er



Tunable CW Titanium:Sapphire Laser @ LNL

from 740 nm to 920 nm , Power higher than 100 mW

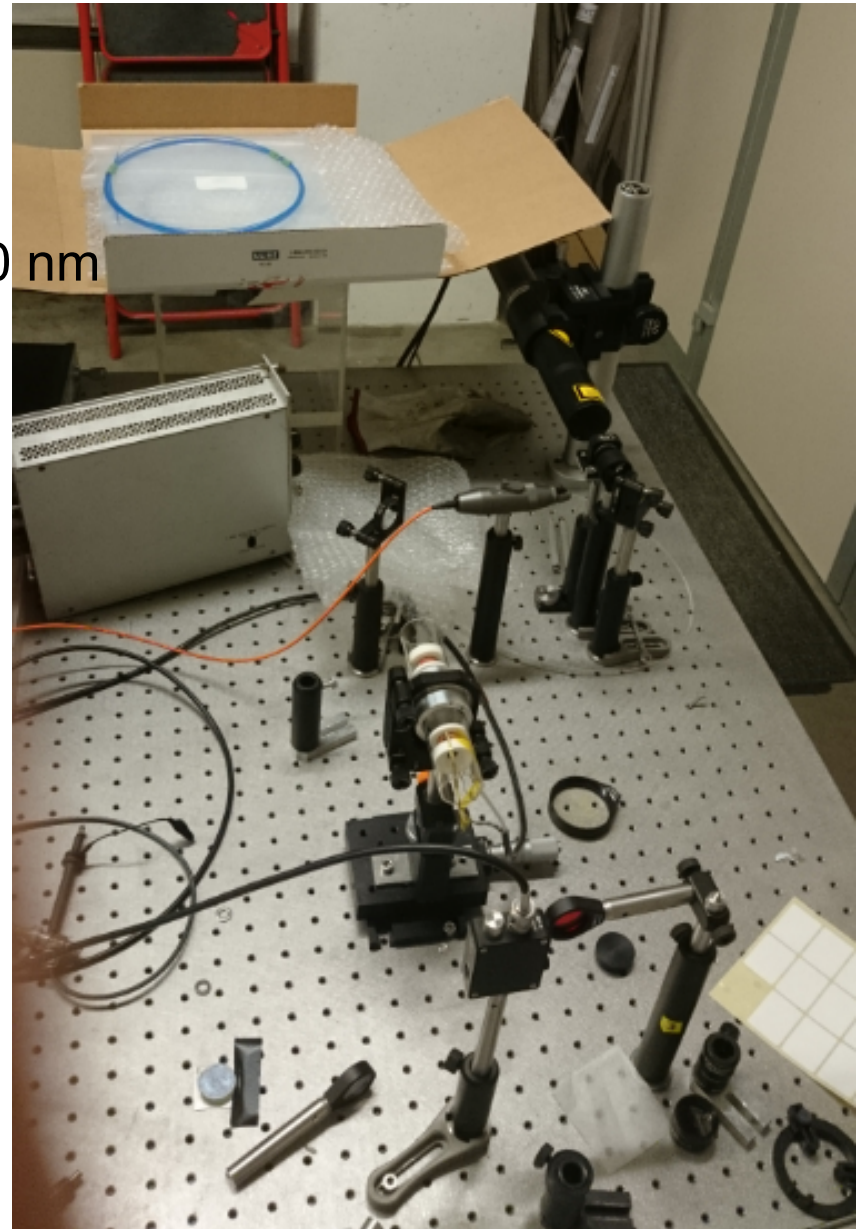


Fabry Perot Wavelength Reference System

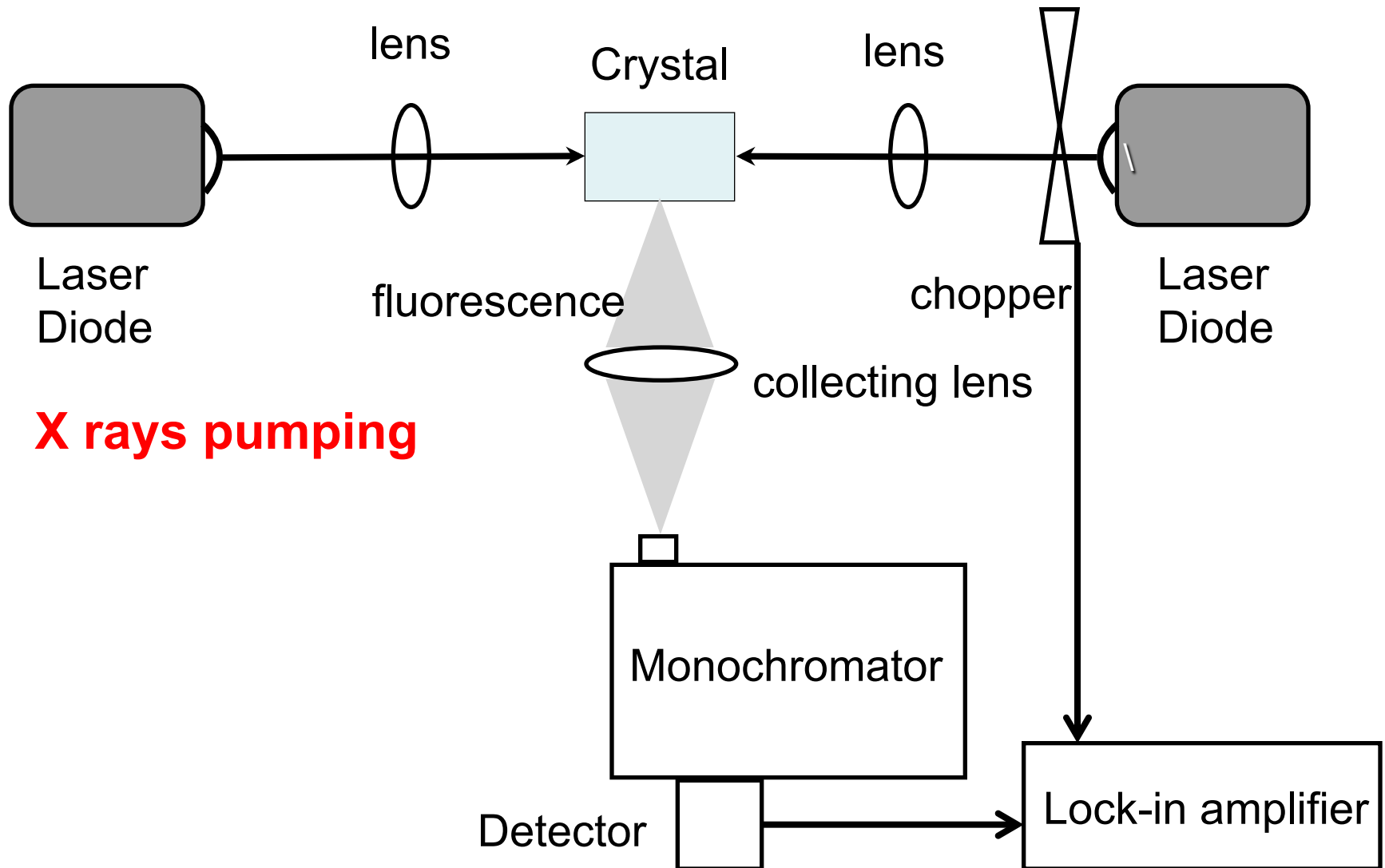
Reference Laser He:Ne P= 1 mW

Cavity Wavelength Acceptance 530 – 870 nm

Wavelength stabilization @ 632,3.. nm



Double resonance experimental apparatus

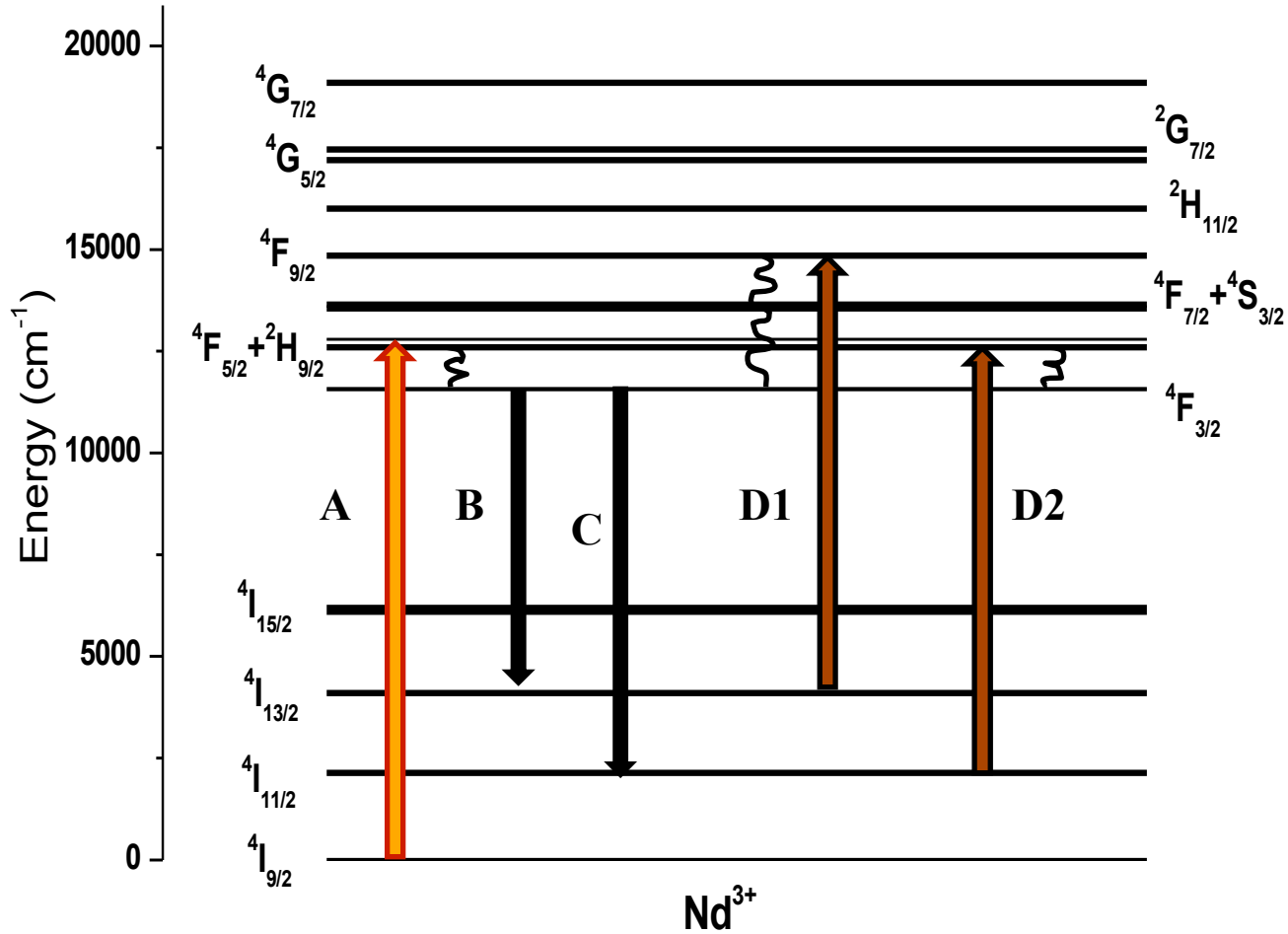


A: Pump@ 808 nm

B: Emission@ 1300 nm

C : Emission @ 1050 nm

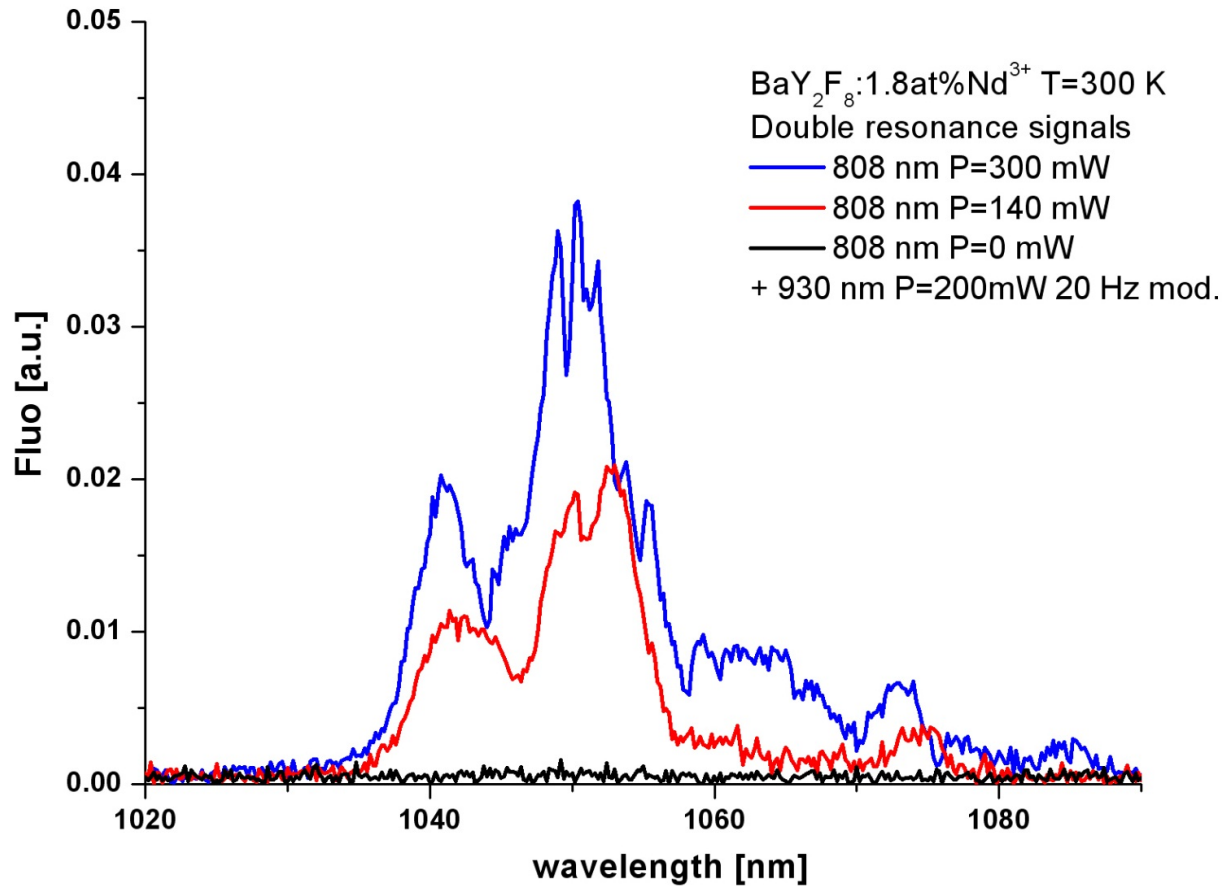
D1, D2 : Pump @ 930 nm



Double Resonance Spectrum

Pump : $^4I_{11/2}$ ----- $^4F_{3/2}$ (930 nm)

Emission: $^4F_{3/2}$ ----- $^4I_{11/2}$ (1050 nm)



Philips Interests in Gamma Induced Stimulated Emission for PET

On the possibility of producing a coherent scintillator

V. K. Lyapidevskii and M. I. Ryazanov

Engineering-Physics Institute, Moscow

(Submitted 22 July 1980)

Pis'ma Zh. Eksp. Teor. Fiz. **32**, No. 8, 516–519 (20 October 1980)

It is shown that a coherent scintillator can, in principle, be produced in an external resonance electromagnetic field.



(19) **United States**

(12) **Patent Application Publication**
Szupryczynski et al.

(10) **Pub. No.:** US 2013/0032722 A1
(43) **Pub. Date:** Feb. 7, 2013

(54) **RADIATION DETECTION WITH OPTICAL AMPLIFICATION**

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(73) **Assignee:** SIEMENS MEDICAL SOLUTIONS USA, INC., Malvern, PA (US)

(21) **Appl. No.:** 13/426,667

(22) **Filed:** Mar. 22, 2012

Related U.S. Application Data

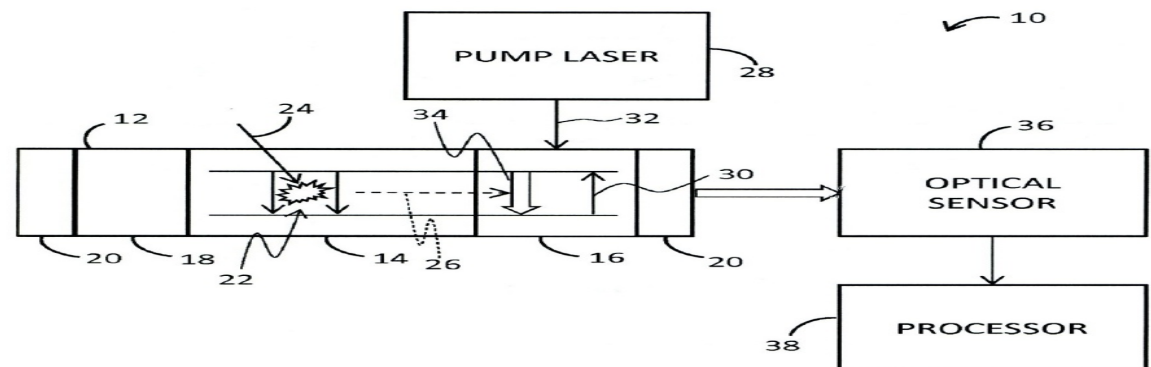
(60) Provisional application No. 61/514,061, filed on Aug. 2, 2011.

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G01T 1/20 (2006.01)
G01T 1/204 (2006.01)

(52) **U.S. Cl.** 250/366; 250/487.1; 250/361 R

(57) **ABSTRACT**
A device for detecting ionizing radiation includes a radiation interaction region configured to generate light in response to an interaction with the ionizing radiation, an optical gain medium region in optical communication with the radiation interaction region and configured to amplify the light, and an energy source coupled to the optical gain medium region and configured to maintain a state of population inversion in the optical gain medium region. The optical gain medium region has an emission wavelength that corresponds with a wavelength of the light generated by the radiation interaction region.



Piano Ricerca 3 Anni:

Studio Combinato:

**Amplificazione Laser su Cristalli
e Risposta alle Radiazioni Ionizzanti**

Attraverso Emissione di Luce di Fluorescenza

Criostato Liquid Helium + Laser Tunabile 1 W + Cristalli + Low Temperature PD

Sezioni : Padova 2,1 FTE, Pisa 1,2 FTE , Cagliari 1,5 FTE

Richieste Finanziarie PD 2015 : 42 Keuro (Criostato ,Laser,Ottica)

Richieste Servizi : 4 MU OM , 4 MU OE

BaY₂F₈: 1.8% Nd³⁺, Nd population density: 9.5 x10²¹ ions/cm³

- **Excited populations**

⁴I_{11/2}: 10¹⁸ ions/cm³

⁴I_{13/2} : 2x10¹⁷ ions/cm³

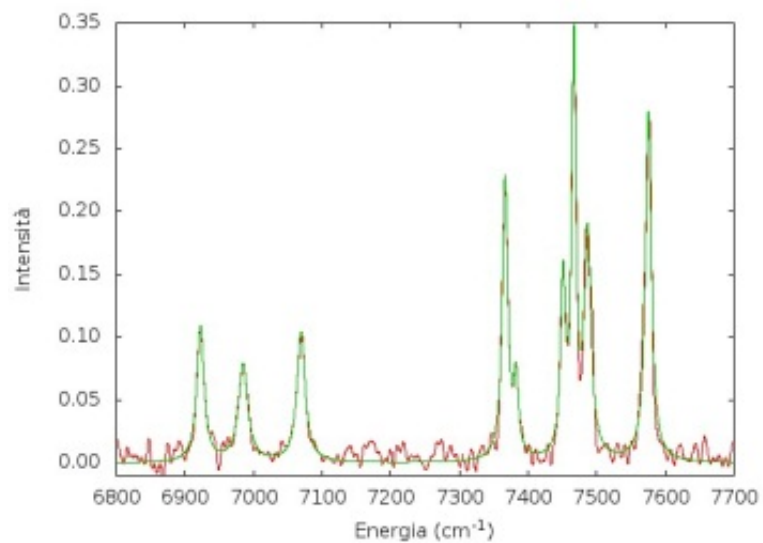
- **Excited population by DR**

⁴I_{11/2} --- ⁴F_{5/2}+²H_{9/2}: 4x10¹⁵ ions/cm³

⁴I_{11/2}---⁴F_{7/2}: 10¹⁴ ions/cm³

${}^4F_{3/2} \rightarrow {}^4I_{15/2}$

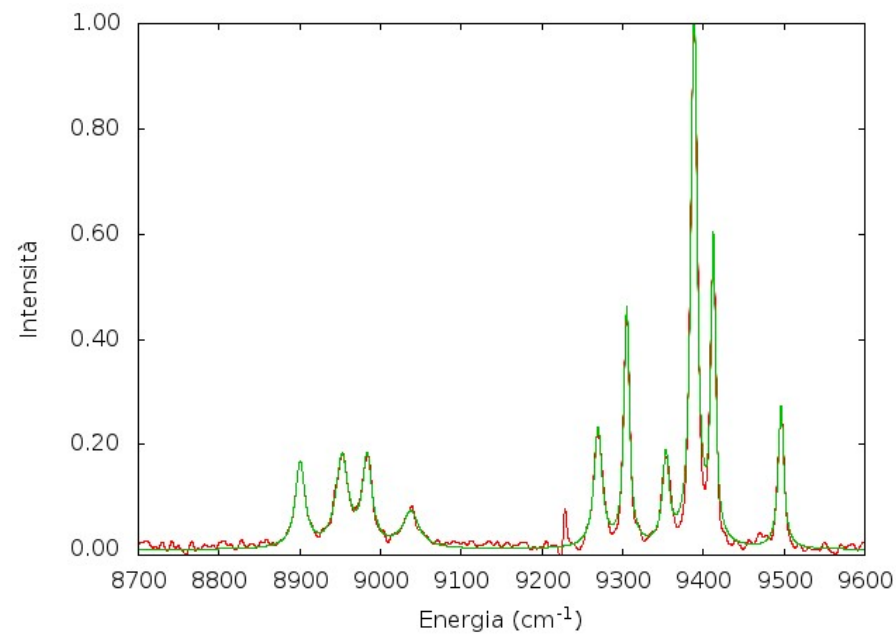
${}^4F_{3/2} \rightarrow {}^4I_{13/2}$



1470 nm

1300 nm

${}^4F_{3/2} \rightarrow {}^4I_{11/2}$



1150 nm

1040 nm